

Hybrid NbTiN-Al MKIDs



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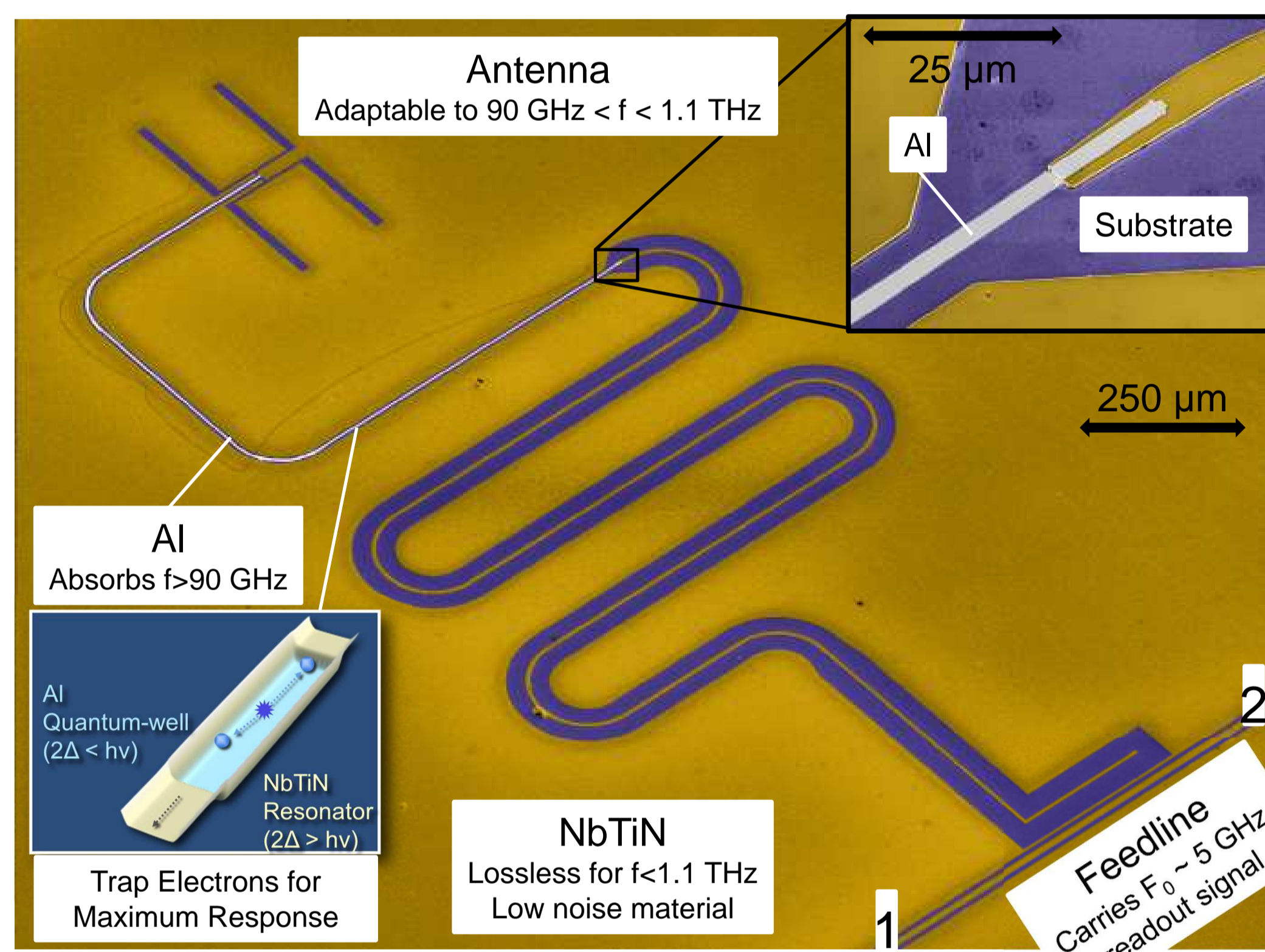
Introduction

Lens-antenna coupled hybrid NbTiN-Al Microwave Kinetic Inductance Detectors (MKIDs) [1] are a detector candidate for large format sub-mm camera's and spectrometers developed in the next decade. For large array development electrical and thermal tests are preferred as initial tests over a full optical evaluation, which requires a time-consuming measurement and a dedicated setup with a controlled illumination source. Based on a simplified model analysis Gao et al. [4] have argued that the change in complex conductivity due to thermally and optically excited quasiparticles is equivalent.

We test the performance of NbTiN-Al MKIDs as well as test the equivalence between their optical and thermal response.

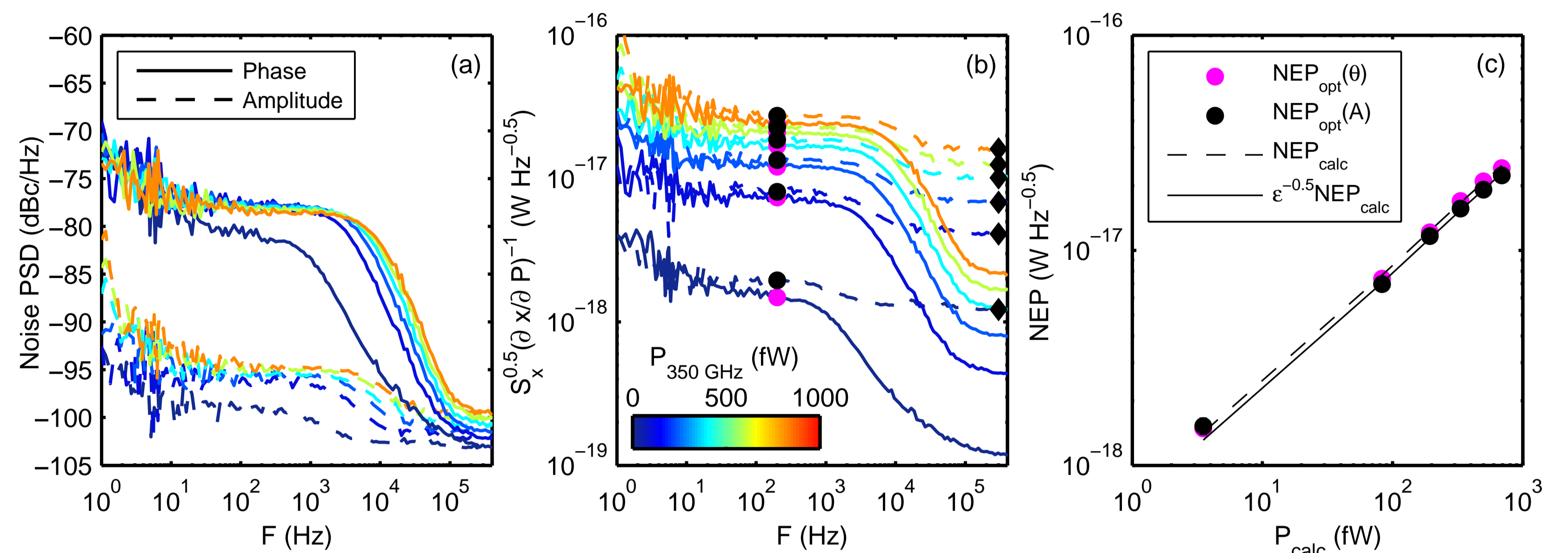
NbTiN-Al MKID Design

The antenna coupled NbTiN-Al MKID design [1] aims to simultaneously **maximize the MKID response** and **minimize the detector noise**.



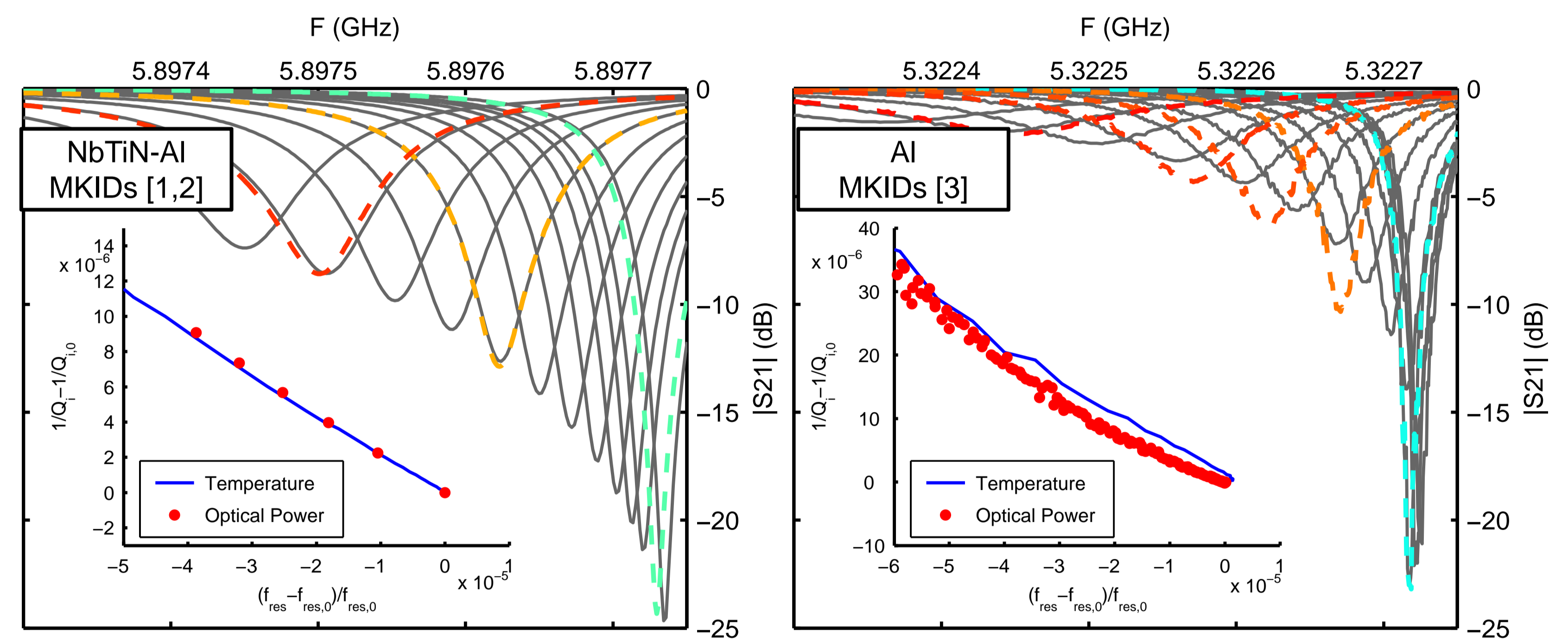
Photon Noise Limited Performance

The antenna coupled NbTiN-Al MKIDs show photon noise limited performance down to 100 fW [1]. Photon noise limited operation can be used to accurately (uncertainty ~5%) determine the optical power absorbed by the MKID and thus verifying its optical reception properties.



MKID Response: Optical versus Thermal

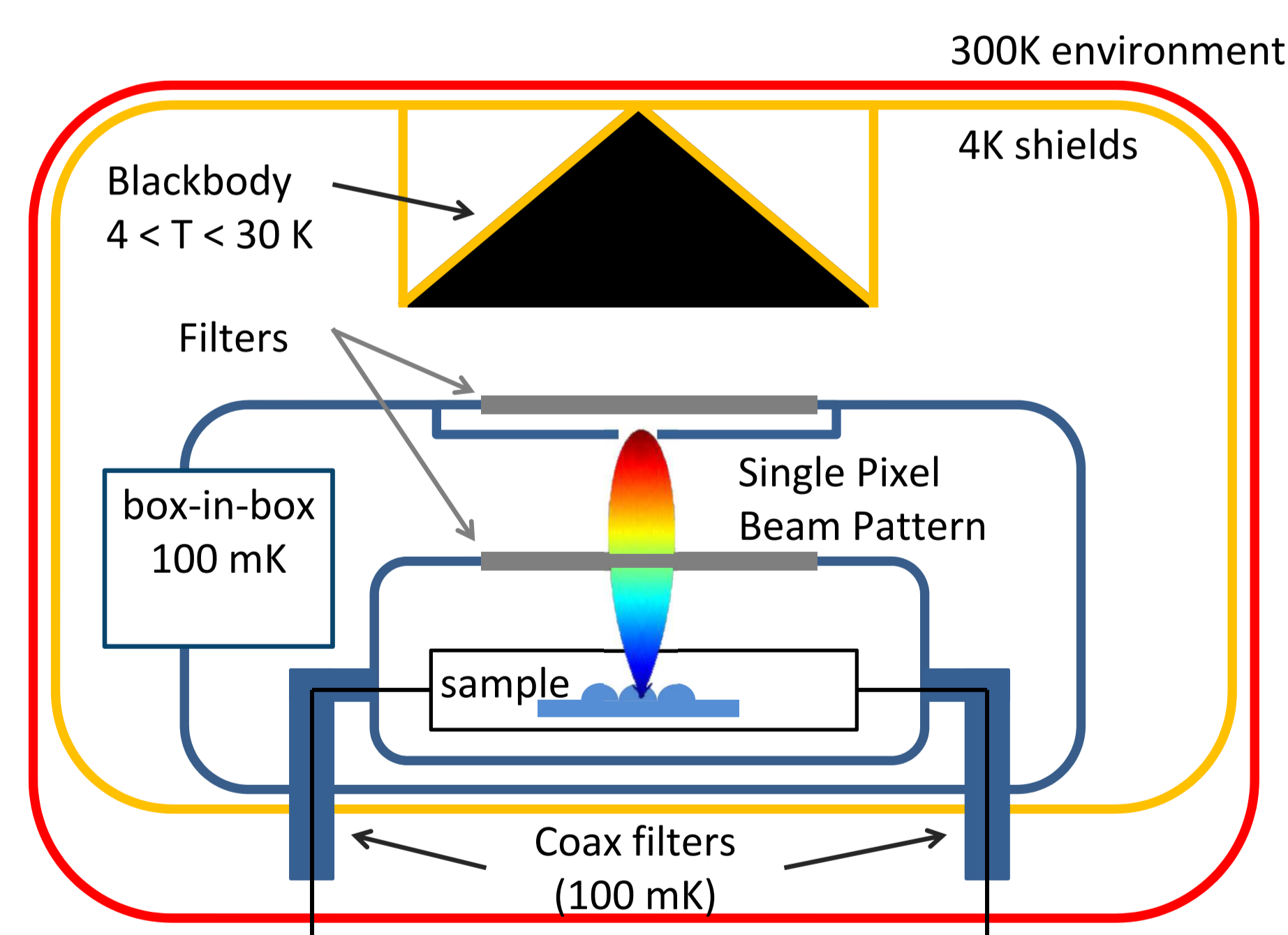
The evolution of the resonance curve as a function of increasing temperature (grey) and increasing optical loading (color).



NbTiN-Al MKIDs: for every optical loading a bath temperature can be found, which produces an identical resonance curve.

Fully Al MKIDs: radiation induces less losses than temperature for the same frequency change.

Experimental Method



In our experiment we use a bath temperature $T_0=100$ mK and blackbody temperature $T_{bb,0}=4.2$ K as initial conditions for both our optical and thermal measurement. Starting from $(T_{bb,0}, T_0)$ we change either T_{bb} or T in the optical or thermal measurement, respectively.

We determine the optical responsivity from a linear fit between the measured change in phase ($x=\theta$) and amplitude ($x=A$) as a function of the absorbed optical power (P_{opt}).

We determine the electrical (dark) responsivity from the measured temperature responsivity, quasiparticle recombination time, pair breaking efficiency and the superconducting transition temperature [2].

$$\frac{\delta x}{\delta P_{dark}} = \frac{\eta_{pb} \tau_{qp}(T)}{\Delta(0, T_c)} \frac{\delta x}{\delta N_{qp}(T, T_c)}$$

We derive Δ from the well-known BCS relation and determine N_{qp} using an integral over the fermi-dirac energy distribution and the BCS density of states.

Conclusions

We have shown that [1,2]:

- Hybrid NbTiN-Al MKIDs are photon noise limited down to 100 fW.
- Thermal and optical excitations have an equivalent effect on the resonance feature of hybrid MKIDs.
- The electrical (dark) responsivity is within a factor of two of the optical responsivity.

We attribute this to the unique geometry of the hybrid NbTiN-Al MKIDs, which integrate a 1 mm long Al absorber in a NbTiN resonator. In different MKID embodiments the equivalence between optical and electrical response is not a priori justified.

In addition, we show that the Optical efficiency can be more accurately be determined from the photon noise (uncertainty ~ 5%) than by comparing the optical and electrical NEP (uncertainty ~15%).

References:

- [1] Janssen et al., Appl. Phys. Lett. (2013)
- [2] Janssen et al., Appl. Phys. Lett. (2014)
- [3] de Visser et al., Nat. Commun. (2014)
- [4] Gao et al., J. Low Temp. Phys. (2008)

| KID No. 1 | Optical | Electrical |
|--------------|--------------------|--------------------|
| $d\theta/dP$ | (4.75 ± 2.0) | (35.5 ± 6.3) |
| dA/dP | (-4.59 ± 0.29) | (-4.29 ± 0.70) |
| KID No. 2 | Optical | Electrical |
| $d\theta/dP$ | (32.7 ± 3.5) | (20.3 ± 3.6) |
| dA/dP | (-3.39 ± 0.37) | (-2.41 ± 0.43) |

Optical and electrical (dark) responsivity for two representative NbTiN-Al MKIDs. Values have been divide by 10^{12} for clarity.